

1700 V EconoDUAL™ 3 modules with TRENCHSTOP™ IGBT7

Aleksei Gurvich Senior Manager Product Definition & Application Engineering LMP PCIM Europe 2022



EconoDUAL™ 3 addresses a broad range of applications including Wind, Drives, Solar and CAV





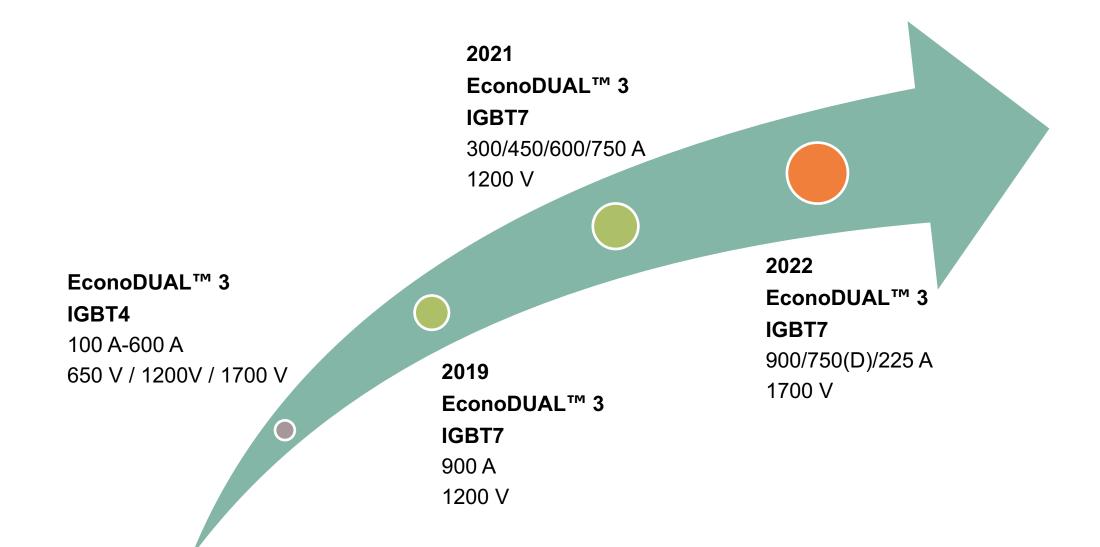
Highlights

- Versatile and popular package
- > Broad product portfolio with proven IGBT4 and IGBT7 technology
- Available with TIM and PressFIT
- Customized products



EconoDUAL™ 3 portfolio is further growing – current extension to 900 A now also available in 1700 V voltage class





EconoDUAL™ 3 with TRENCHSTOP™ IGBT7



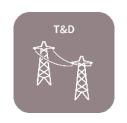
Key Features

- > 900 A 1700 V best-in-class EconoDUAL™ 3
- > 750 A 1700 V EconoDUAL™ 3 with enlarged diode as best fit for Wind and SVG applications
- → TRENCHSTOP™ IGBT7 technology
- Improved EconoDUAL™ 3 housing
- Lower conduction and switching losses
- > Higher inverter output current for the same frame size
- Reduced system costs by avoiding paralleling of the modules

Typical Applications







Target Product Portfolio	
IC [A]	1700 V
900	FF900R17ME7_B11*
750	FF750R17ME7_B11
	FF750R17ME7D_B11**
600	FF600R17ME7_B11
450	FF450R17ME7_B11
300	FF300R17ME7_B11
225	FF225R17ME7_B11*

^{*} already available

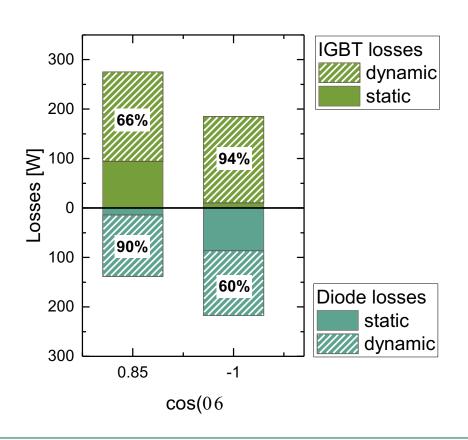
^{**} with enlarged diode optionally available with TIM





Typical application conditions for 1700 V IGBT modules Dynamic losses are dominating





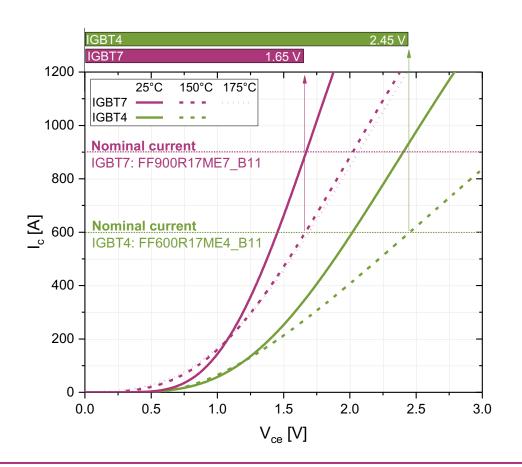
Power losses ratio for the FF600R17ME4_B11 under the following conditions:

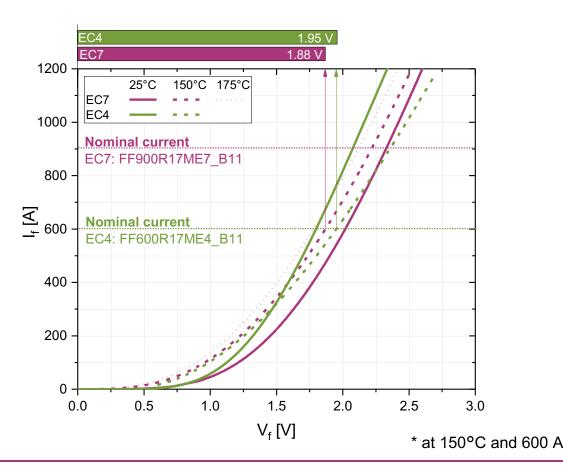
- $f_{sw} = 2.5 \text{ kHz}$
- $I_{rms} = 175 A$
- $\cos(\varphi) = 0.85 / -1$
- \rightarrow m = 1
- $f_{out} = 50 \text{ Hz}$
- $V_{dc} = 1150 \text{ V}$
- forced air cooling

- > Dynamic losses have a major share at both $cos(\phi) = 0.85$ and $cos(\phi) = -1$
- To optimize the electrical performance it is crucial to reduce switching losses
- > Well-balanced switching and static parameters of the IGBT and the diode should not be neglected

Static losses comparison Significantly reduced IGBT static loss compared to former generation





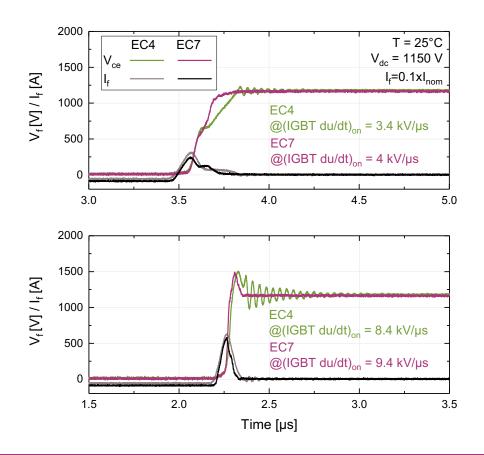


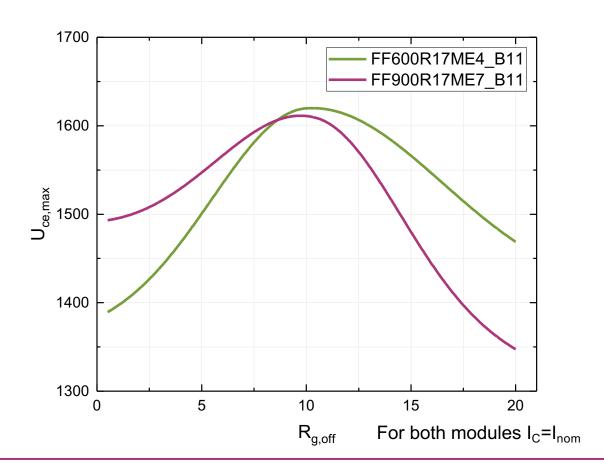
FF900R17ME7_B11 with TRENCHSTOP™ IGBT7 1700 V shows:

- > 33% lower IGBT static losses*
- > 4% lower diode static losses*

Diode softness and IGBT overvoltage at turn-off Safe and smooth switching over a wide operating range



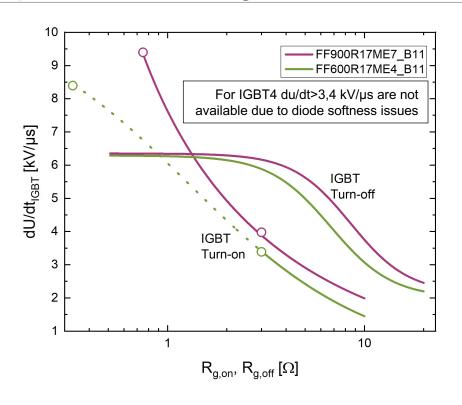


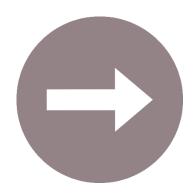


- Improved softness of EC7 diode allows clean switching even at high du/dt
- > IGBT7 is able to turn-off **50%** higher current with the same U_{ce,max} level

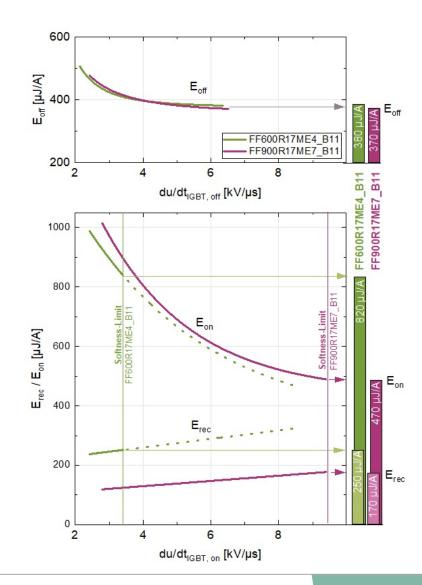
du/dt controllability and dynamic losses Improved switching losses for both IGBT and diode





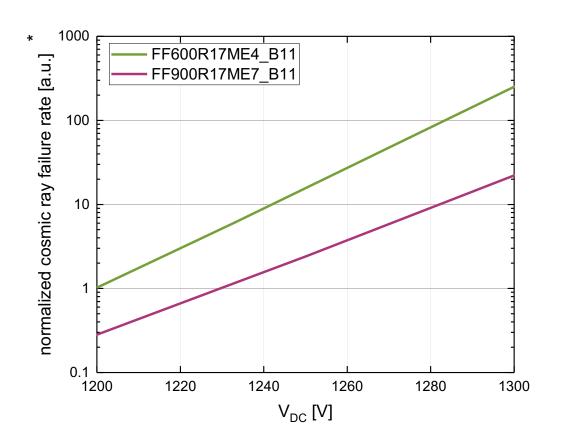


- Wider du/dt range leads to more than 40% lower turn-on losses IGBT7 vs IGBT4
- The new EC7 diode shows 50% Erec reduction when switching at the same du/dt



Cosmic ray induced FIT rate Up to one order of magnitude CR FIT improvement



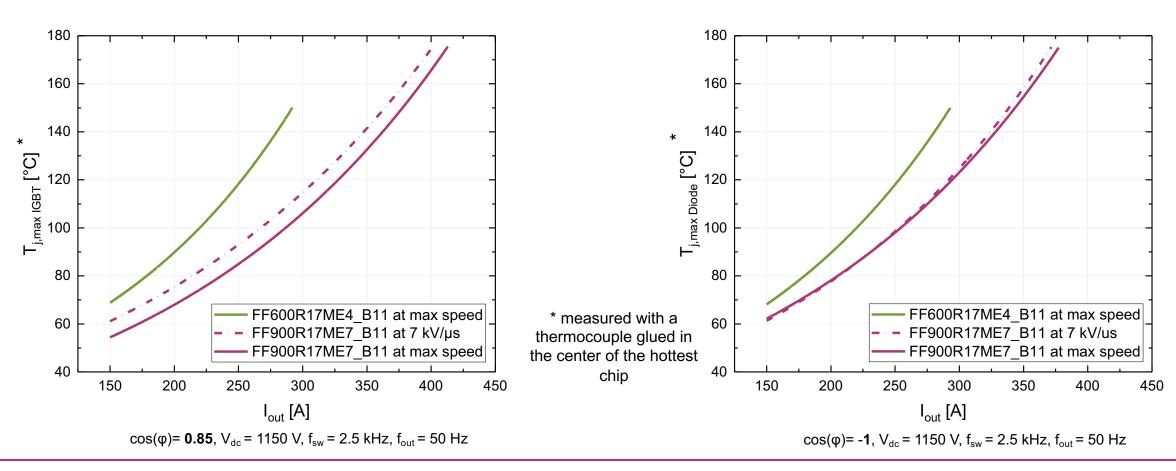


- > Factor of 3 CR FIT improvement at 1200 V
- > One order of magnitude reduced CR FIT at 1300 V

* at 25°C

Application test results: drives and AFE Higher current densities with IGBT7



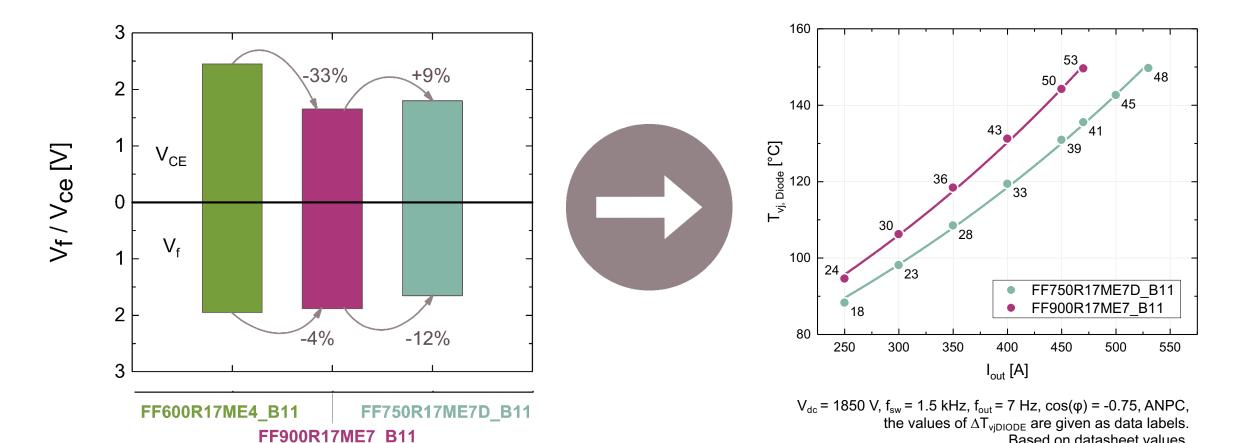


FF900R17ME7_B11 with TRENCHSTOP™ IGBT7 1700 V shows:

- **y up to 41%** higher output current at $\cos(\phi) = 0.85$
- **y up to 30%** higher output current at $cos(\phi) = -1$

FF750R17ME7D B11 with enlarged diode: performance gain in V_F-demanding applications





- > 12% lower V_F and 16% lower R_{thJC,DIODE} compared to the FF900R17ME7_B11 translate into:
- > 13% higher output current in rotor-side converter with DFIG
- > 4,6 times higher quantity of turn-on/off cycles at same I_{out} = 470 A

Based on datasheet values.

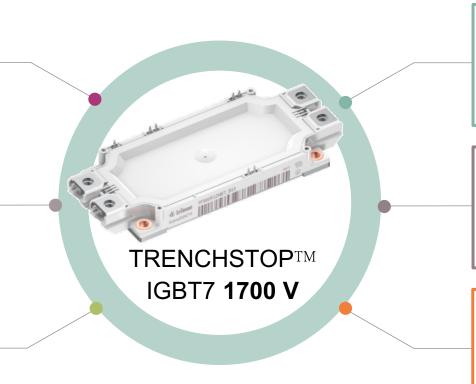




1. Lower conduction and switching losses

2. Enhanced controllability of du/dt and diode softness

3. Overload capability at Tvj,op=175°C



4. FF750R17ME7D_B11 with reduced VF and diode R_{th}

5. Improved cosmic ray robustness

6. Higher power densities in a wide variety of applications



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